

T493B226K010BT6110

T493 HRA, Tantalum, MnO₂ Tantalum, HRA, 22 uF, 10%, 10 VDC, SMD, MnO₂, Molded, DLA Drawing, B (0.1%/1000 Hrs), 3 Ohms, 3528, 2.1 mm, 0.8 mm



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General Information

Series	T493 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, DLA Drawing
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	102.3 mg

Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

Specifications

Capacitance	22 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	3 Ohms (100kHz 25C)
Ripple Current	158 mA (rms, 100kHz 25C)
Leakage Current	2.2 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

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